

LF111/LF211/LF311 Voltage Comparators

General Description

The LF111, LF211 and LF311 are FET input voltage comparators that virtually eliminate input current errors. Designed to operate over a 5.0V to $\pm 15V$ range the LF111 can be used in the most critical applications.

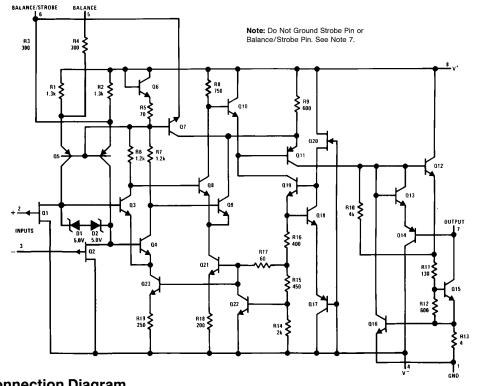
The extremely low input currents of the LF111 allows the use of a simple comparator in applications usually requiring input current buffering. Leakage testing, long time delay circuits, charge measurements, and high source impedance voltage comparisons are easily done.

Further, the LF111 can be used in place of the LM111 eliminating errors due to input currents. See the "application hints" of the LM311 for application help.

Features

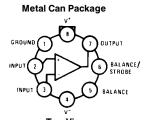
- Eliminates input current errors
- Interchangeable with LM111
- No need for input current buffering

Schematic Diagram



Connection Diagram





Top View Order Number LF111H, LF111H-MIL or LF311H See NS Package Number H08C

TL/H/5703-1

Absolute Maximum Ratings

If Military/Aerospace specified devices are required	,				
please contact the National Semiconductor Sales	š				
Office/Distributors for availability and specifications.					
(Nata 0)					

(Note 8)		
,	LF111/LF211	LF311
Total Supply Voltage (V ₈₄)	36V	36V
Output to Negative Supply Voltage (V ₇₄)	50V	40V
Ground to Negative Supply		
Voltage (V ₁₄)	30V	30V
Differential Input Voltage	$\pm 30V$	$\pm 30V$
Input Voltage (Note 1)	$\pm15V$	± 15V
Power Dissipation (Note 2)	500 mW	500 mW
Output Short Circuit Duration	10 seconds	10 seconds

	LF111/LF211	LF311
Operating Temp.		
Range		
LF111	$-55^{\circ}\text{C to} + 125^{\circ}\text{C}$	
LF211	-25°C to $+85$ °C	
LF311		0°C to +70°C
Storage Temp.		
Range	$-65^{\circ}\text{C to} + 150^{\circ}\text{C}$	$-65^{\circ}\text{C to} + 150^{\circ}\text{C}$
Lead Temp.		
(Soldering,		
10 seconds)	260°C	260°C

ESD rating to be determined.

Electrical Characteristics (LF111/LF211) (Note 3)

Parameter Conditions		Min	Тур	Max	Units
Input Offset Voltage (Note 4)	$T_A = 25$ °C, $R_S \le 50$ k		0.7	4.0	mV
Input Offset Current (Note 4)	T _A =25°C, V _{CM} =0 (Note 6)		5.0	25	pА
Input Bias Current	T _A =25°C, V _{CM} =0 (Note 6)		20	50	pА
Voltage Gain	T _A =25°C	40	200		V/mV
Response Time (Note 5)	T _A =25°C		200		ns
Saturation Voltage	$V_{IN} \le -5.0 \text{ mV}, I_{OUT} = 50 \text{ mA}, T_A = 25^{\circ}\text{C}$		0.75	1.5	V
Strobe On Current	T _A =25°C		3.0		mA
Output Leakage Current	$V_{IN} \le 5.0 \text{ mV}, V_{OUT} = 35 \text{V}, T_A = 25 ^{\circ}\text{C}$		0.2	10	nA
Input Offset Voltage (Note 4)	$R_S \le 50k$			6.0	mV
Input Offset Current (Note 4)	$V_S = \pm 15V, V_{CM} = 0 \text{ (Note 6)}$		2.0	3.0	nA
Input Bias Current	$V_S = \pm 15V, V_{CM} = 0 \text{ (Note 6)}$		5.0	7.0	nA
Input Voltage Range		-13.5	±14	13.0	V
Saturation Voltage	$V^{+} \ge 4.5V, V^{-} = 0$ $V_{1N} \le -6.0 \text{ mV}, I_{OUT} \le 8.0 \text{ mA}$		0.23	0.4	٧
Output Leakage Current	V _{IN} ≥5.0 mV, V _{OUT} =35V		0.1	0.5	μΑ
Positive Supply Current	T _A =25°C		5.1	6.0	mA
Negative Supply Current	T _A =25°C		4.1	5.0	mA

Note 1: This rating applies for \pm 15V supplies. The positive input voltage limit is 30V above the negative supply. The negative input voltage limit is equal to the negative supply voltage or 30V below the positive supply, whichever is less.

Note 2: The maximum junction temperature of the LF111 is +150°C, the LF211 is +110°C and the LF311 is +85°C. For operating at elevated temperatures, devices in the H08 package must be derated based on a thermal resistance of +65°C/W junction to ambient (in 400 linear feet/min air flow), +165°C/W junction to ambient (in static air), or +20°C/W junction to case.

Note 3: These specifications apply for $V_S = \pm 15V$, and the Ground pin at ground, and $-55^{\circ}C \le T_A \le +125^{\circ}C$ for the LF111, unless otherwise stated. With the LF211, however, all temperature specifications are limited to $-25^{\circ}C \le T_A \le \pm 85^{\circ}C$ and for the LF311 $0^{\circ}C \le T_A \le +70^{\circ}C$. The offset voltage, offset current and bias current specifications apply for any supply voltage from a single 5.0V supply up to $\pm 15V$ supplies.

Note 4: The offset voltages and offset currents given are the maximum values required to drive the output within a volt of either supply with a 1.0 mA load. Thus, these parameters define an error band and take into account the worst case effects of voltage gain and input impedance.

 $\textbf{Note 5:} \ \text{The response time specified (see definitions) is for a 100 mV input step with 5.0 mV overdrive.}$

Note 6: For input voltages greater than 15V above the negative supply the bias and offset currents will increase—see typical performance curves.

Note 7: This specification gives the current that must be drawn from the strobe pin to ensure the output is properly disabled. Do not short the strobe pin to ground; it should be current driven at 3 to 5 mA.

Note 8: Refer to RETSF111X for LF111H military specifications.

Ε	lectrica	il Chara	cterist	tics (LF311) (Note 3)

Parameter	Conditions	Min	Тур	Max	Units
Input Offset Voltage (Note 4)	$T_A = 25^{\circ}C, R_S \le 50k$		2.0	10	mV
Input Offset Current (Note 4)	T _A =25°C, V _{CM} =0 (Note 6)	T _A =25°C, V _{CM} =0 (Note 6)		75	pA
Input Bias Current	T _A =25°C, V _{CM} =0 (Note 6)		25	150	pA
Voltage Gain	T _A =25°C		200		V/mV
Response Time (Note 5)	T _A =25°C		200		ns
Saturation Voltage	$V_{IN} \le -10 \text{ mV}, I_{OUT} = 50 \text{ mA}, T_A = 25^{\circ}\text{C}$		0.75	1.5	V
Strobe On Current	T _A =25°C		3.0		mA
Output Leakage Current	V _{IN} ≥10mV, V _{OUT} =35V, T _A =25°C		0.2	10	nA
Input Offset Voltage (Note 4)	R _S ≤50k			15	mV
Input Offset Current (Note 4)	$V_S = \pm 15V, V_{CM} = 0 \text{ (Note 6)}$	±15V, V _{CM} =0 (Note 6)			nA
Input Bias Current	V _S =15V, V _{CM} =0 (Note 6)		3.0		nA
Input Voltage Range			+14 -13.5		V V
Saturation Voltage	$V^{+} \ge 4.5V, V^{-} = 0$ $V_{IN} \le -10 \text{ mV}, I_{OUT} \le 8.0 \text{ mA}$		0.23	0.4	V
Positive Supply Current	T _A =25°C		5.1	7.5	mA
Negative Supply Current	T _A =25°C		4.1	5.0	mA

Note 1: This rating applies for ±15V supplies. The positive input voltage limit is 30V above the negative supply. The negative input voltage limit is equal to the negative supply voltage or 30V below the positive supply, whichever is less.

Note 2: The maximum junction temperature of the LF111 is +150°C, the LF211 is +110°C and the LF311 is +85°C. For operating at elevated temperatures, devices in the H08 package must be derated based on a thermal resistance of +165°C/W, junction to ambient, or +20°C/W, junction to case.

Note 3: These specifications apply for $V_S = \pm 15V$ and $-55^{\circ}C \le T_A \le +125^{\circ}C$ for the LF111, unless otherwise stated. With the LF211, however, all temperature specifications are limited to $-25^{\circ}C \le T_A \le +85^{\circ}C$ and for the LF311 $0^{\circ}C \le T_A \le +70^{\circ}C$. The offset voltage, offset current and bias current specifications apply for any supply voltage from a single 5.0 mV supply up to $\pm 15V$ supplies.

Note 4: The offset voltages and offset currents given are the maximum values required to drive the output within a volt of either supply with a 1.0 mA load. Thus, these parameters define an error band and take into account the worst case effects of voltage gain and input impedance.

Note 5: The response time specified (see definitions) is for a 100 mV input step with 5.0 mV overdrive.

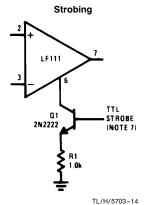
Note 6: For input voltages greater than 15V above the negative supply the bias and offset currents will increase—see typical performance curves.

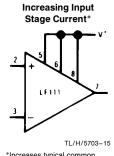
Note 7: This specification gives the current that must be drawn from the strobe pin to ensure the output is properly disabled. Do not short the strobe pin to ground; it should be current driven at 3 to 5 mA.

Auxiliary Circuits

Offset Balancing
R2
3.0k
R1
LF111

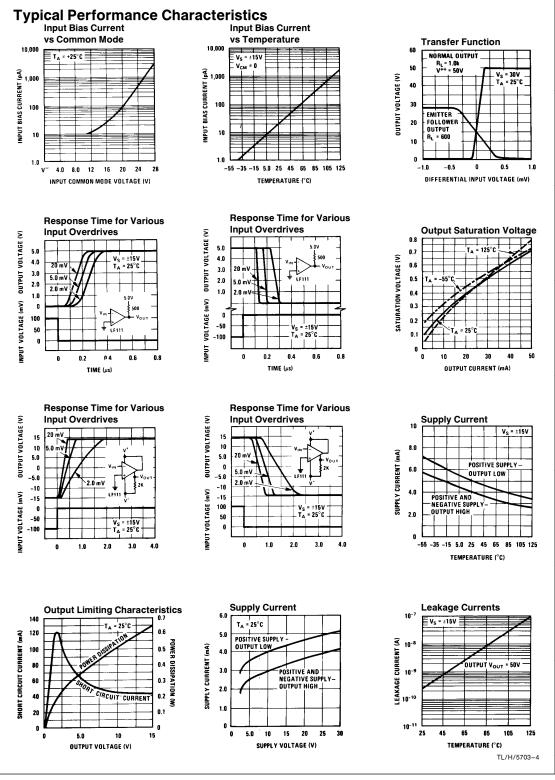
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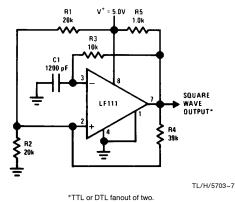
*Increases typical common mode slew from 7.0V/ μ s to 18V/ μ s

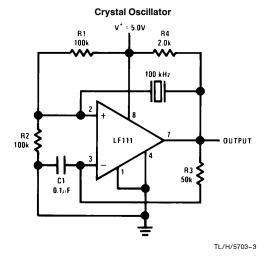
Note: Do Not Ground Strobe Pin.



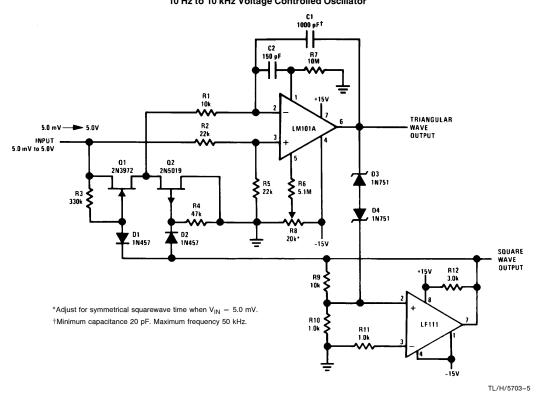
Typical Applications

100 kHz Free Running Multivibrator



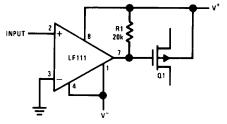


10 Hz to 10 kHz Voltage Controlled Oscillator



Typical Applications (Continued) Frequency Doubler Output—10 kHz to 50 kHz Output—10 kHz to 100 kHz Frequency Radius (Continued) Frequency Doubler Frequency Doubler Output—10 kHz to 50 kHz Output—10 kHz to 100 kHz

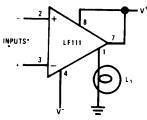
Zero Crossing Detector Driving MOS Switch



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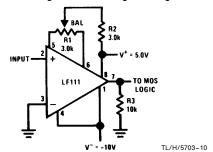
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Driving Ground-Referred Load

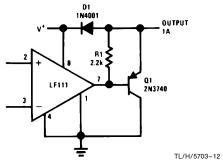


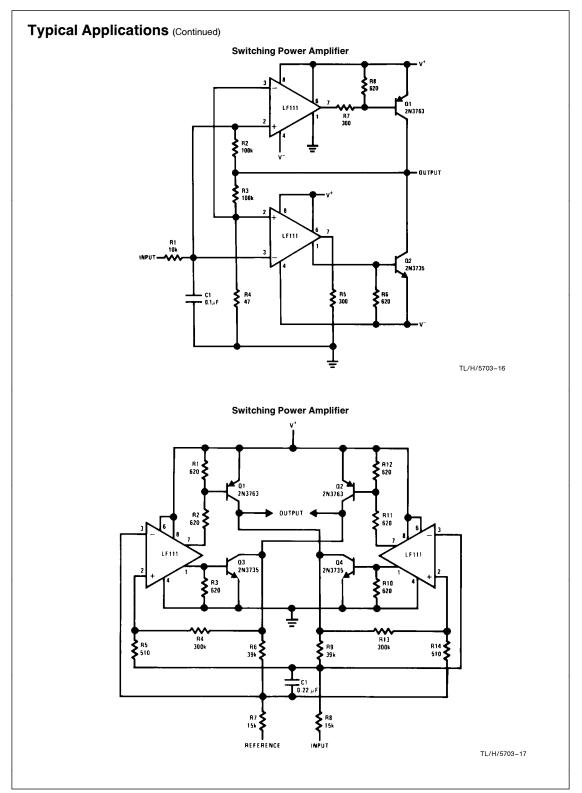
*Input polarity is reversed when using pin 1 as output.

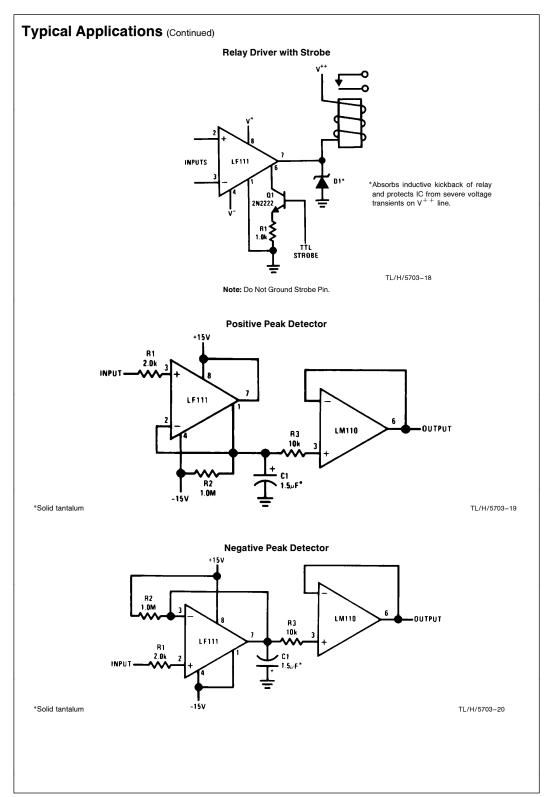
Zero Crossing Detector Driving MOS Logic



Comparator and Solenoid Driver

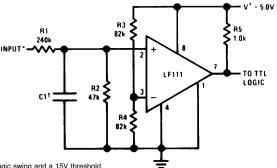






Typical Applications (Continued)

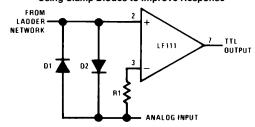
TTL Interface with High Level Logic



*Values shown are for a 0 to 30V logic swing and a 15V threshold.

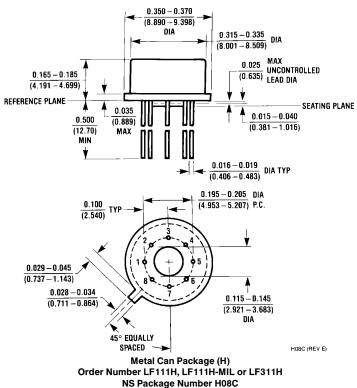
 $\dagger \text{May}$ be added to control speed and reduce susceptibility to noise spikes

Using Clamp Diodes to Improve Response



TL/H/5703-21

Physical Dimensions inches (millimeters)



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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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